



100V PNP MEDIUM POWER TRANSISTOR IN TO252

Features

- BV_{CEO} > -100V
- I_C = -6A Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Complementary NPN Type: MJD41CQ
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
 The DIODES™ MJD42CQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

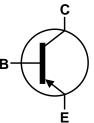
Mechanical Data

- Package: TO252 (DPAK)
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.34 grams (Approximate)

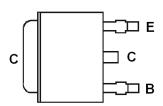




Top View



Device Schematic



Pin Out Configuration Top View

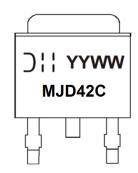
Ordering Information (Note 4)

Part Number	Pookogo	Marking Reel size (inches)		Tape width (mm)	Packing		
Fait Nulliber	Package	war King	Reel Size (Iliches)	rape width (IIIII)	Qty.	Carrier	
MJD42CQ-13	TO252	MJD42C	13	16	2,500	Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



MJD42C = Product Type Marking Code

OH = Manufacturers' Code Marking

YYWW = Date Code Marking

YY = Last Digit of Year (ex: 22 = 2022)

WW = Week Code (01 - 53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-120	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-6	A
Peak Pulse Collector Current	Ісм	-10	A
Continuous Base Current	I _B	-2	A

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.70		
Power Dissipation	(Note 6)	P _D	P _D 2.40		
	(Note 7)		1.50		
	(Note 5)		46		
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	52	°C/W	
	(Note 7)		83		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the exposed collector pad on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics

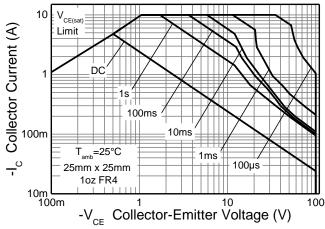


Figure 1. Safe Operating Area

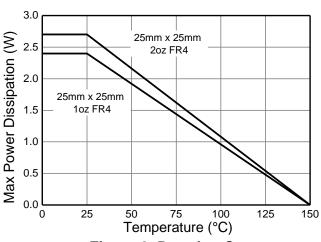


Figure 2. Derating Curve

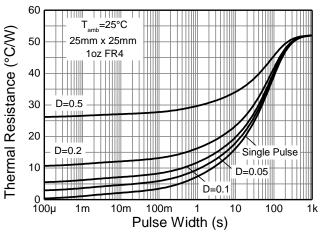


Figure 3. Transient Thermal Impedance

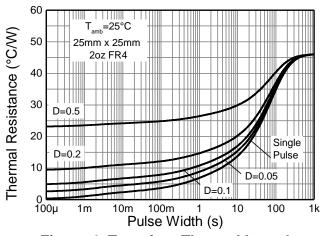


Figure 4. Transient Thermal Impedance

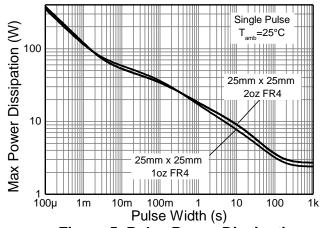


Figure 5. Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-120	_		V	$I_C = -100uA$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-100	_		V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	_	_	V	I _E = -100uA
Collector Cut-off Current	I _{CES}	_	_	-1	uA	V _{CE} = -100V
Collector-Base Cut-off Current	I _{CBO}	_	_	-100	nA	V _{CB} = -100V
Emitter Cut-off Current	I _{EBO}	_	_	-1	uA	$V_{EB} = -6V$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	_	_	-1.5	V	I _C = -6A, I _B = -600mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	_	-1.4	V	I _C = -6A, I _B = -600mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	-2	V	$I_{C} = -6A$, $V_{CE} = -4V$
DC Current Gain (Note 9)	h _{FE}	30	_			$V_{CE} = -4V, I_{C} = -0.3A$
De Guiteili Gaiii (Note 9)	I I FE	15	_			$V_{CE} = -4V$, $I_C = -3A$
Small Signal Current Gain	h _{fe}	20	_	_	_	$V_{CE} = -10V$, $I_{C} = -0.5A$, $f = 1kHz$
Current Gain-Bandwidth Product	f _T	3	_		MHz	$I_C = -0.5A$, $V_{CE} = -10V$, $f = 100MHz$
Output Capacitance	C _{obo}	_	185		pF	$V_{CB} = -10V$, $f = 1MHz$
Input Capacitance	C _{ibo}	_	80	_	pF	$V_{EB} = -0.5V, f = 1MHz$
Delay Time	t _d	_	3	_	ns	
Rise Time	t _r	_	209	_	ns	$I_C = -2A$, $V_{CC} = -10V$
Storage Time	ts	_	183	_	ns	$-I_{B1} = I_{B2} = -200 \text{mA}$
Fall Time	t _f	_	623	_	ns	

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

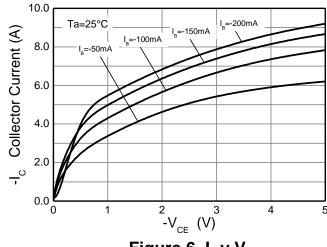


Figure 6. $I_{c} v V_{ce}$

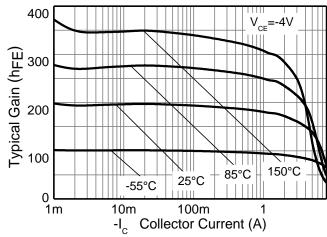


Figure 7. $h_{FE} V I_{C}$

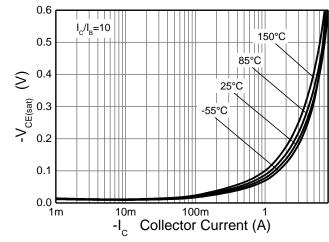


Figure 8. V_{CE(sat)} v I_C

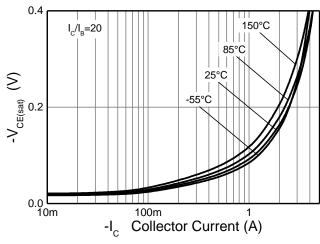
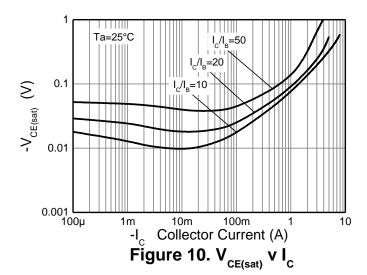


Figure 9. V_{CE(sat)} v I_C



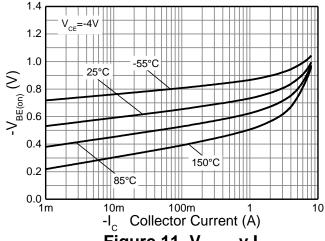


Figure 11. V_{BE(on)} v I_C



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

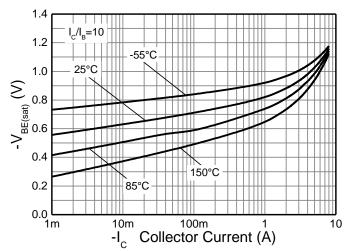


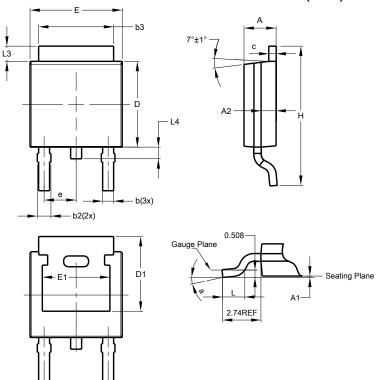
Figure 12. $V_{BE(sat)} V I_{C}$



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

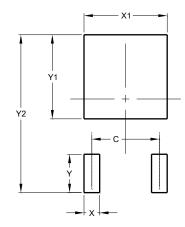


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.286 BSC				
Е	6.45	6.70	6.58		
E1	4.32				
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10.700		



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